**Raman Spectra and Microstructure of Zinc Oxide irradiated with Swift Heavy Ion**

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**Abstract:** Zinc oxide (ZnO) materials irradiated with 350 MeV $^{56}$Fe$^{21+}$ ions were studied by Raman spectroscopy, Photoluminescence spectra (PL) and Transmission electron microscope (TEM). After $^{56}$Fe$^{21+}$ ion irradiation, a strong oxygen vacancy (V$_o$) related defect absorption peak at 576 cm$^{-1}$ and an interstitial zinc (Zn$_i$)-related defect at 80 cm$^{-1}$~200 cm$^{-1}$ formed, and with the increase of dose, the absorption peak was obviously enhanced. Through theoretical calculation, different Raman incident light test methods were used to determine the oxygen vacancy defect (V$_o$). There were no significant variation tendencies in the other Raman characteristic lines. Our results demonstrate an energy loss process contributing to the defect structure during irradiation. TEM images showed a lot of fundamental defects. But we see no distinct amorphization in the samples in the electron diffraction images, indicating that the higher energy and irradiation dose hardly affected the structure and performance of zinc oxide.

**Keywords:** swift heavy ion; irradiation; TEM; Raman

1. **Introduction**

ZnO is a kind of typical II–IV group elements oxide material, due to its excellent optical and electrical properties. Thus, it has received wide attention from the scientific community. Because of its simple synthesis and the possibility of optoelectronic integration, the application of ZnO in nano-electronics and nano-photonics [1–4] is very promising. In addition, ZnO has great application potential in ultraviolet laser devices and nano-photonics devices [5–7]. The research of related ZnO materials is mainly focused on voltage-dependent, gas sensing characteristics, the photocatalytic properties of nanomaterials [8,9], NiO/ZnO heterojunction ultraviolet detectors, and low dimensional ZnO heterojunction light emitting diodes, etc. [10–12]. There is relatively little research on the structural properties of ZnO materials in a strong radiation environment. There are few studies on the structural properties of Zinc oxide materials irradiated with energetic swift heavy ions.

Zinc oxide irradiated with swift heavy ions has been used to study the changes of the internal structure in detail by means of Raman spectra, Photoluminescence spectra (PL) and Transmission electron microscope (TEM). Researches on radiation resisting properties have important practical uses for the application of zinc oxide-related products in the aerospace industry in the years to come.

2. **Experimental Procedure**

The experimental samples for the commercial “O” surface polishing comprised zinc oxide single crystals with a surface normal direction of [0001] and an edge orientation of [11–20] (10 × 10 × 0.5 mm). The 350 MeV $^{56}$Fe$^{21+}$ ion irradiation test was carried out at the Heavy Ions Research Facility in Lanzhou (HIRFL) at room temperature. The SRIM 2013 code theoretically calculated that the incidence depth of the 350 MeV $^{56}$Fe$^{21+}$ ions in the ZnO is about 32.6 µm. The samples were irradiated in a target chamber...
with a vacuum of $5 \times 10^{-5}$ Pa. The beam strength was 500 nA and beam spot area was $\Phi 15$ mm. Raman spectra adopted 532 nm lasers and measured from 80–660 cm$^{-1}$. The scanning time at each point was 30 s. The PL spectra were obtained with 340 nm excitation light. TEM samples were prepared using the focusing ion beam technique. The microstructure of the irradiated zone was examined using a Jeol 200 CX microscope operated at 200 kV (SJEM-2100F JEOL, Japan).

3. Results and Discussion

3.1. Raman Spectra of $^{56}$Fe$^{21+}$ Ion-Irradiated ZnO

The Raman spectra of $^{56}$Fe$^{21+}$ ion irradiated and unirradiated zinc oxide single crystals are provided in Figure 1. The Raman peaks are shown by the corresponding atomic oscillations in the middle picture of Figure 1, with the red arrows specifying the leading atomic shift direction. The incident light of the Raman laser were directed along the axis [0001] orientation. The eigenmode of $E_2$(low), $E_2$(high) and $A_1$(LO) of unirradiated ZnO samples were located at 101 cm$^{-1}$, 437 cm$^{-1}$ and 576 cm$^{-1}$, respectively. The $2E_2$(low) and $E_2$(high)-$E_2$(low) modes emerged at 202 cm$^{-1}$ and 333 cm$^{-1}$, respectively [13]. After irradiated by $^{56}$Fe$^{21+}$ ions, wide absorption bands of 80 cm$^{-1}$–245 cm$^{-1}$ and 520 cm$^{-1}$–600 cm$^{-1}$ emerged. The 80 cm$^{-1}$–245 cm$^{-1}$ were affected by interstitial zinc ($Zn_i$) [14,15]. The 520 cm$^{-1}$–600 cm$^{-1}$ were generated by the oxygen vacancy defect ($V_o$) [16–18]. Since the characteristic vibration peaks associated with oxygen vacancy ($V_o$) defect at 576 cm$^{-1}$ completely overlapped with the eigenmode of $A_1$(LO), it was very difficult to confirm whether the strong vibration absorption peaks at 576 cm$^{-1}$ were caused by $A_1$(LO). According to the analysis of Raman scattering intensity of phonons based on Lattice dynamics theory, when the incident light was perpendicular to the axis [0001] of the crystal for Raman spectrum measurement, the $A_1$(LO) vibration mode did not appear. Figure 2 shows the Raman scattering spectra of the specimen irradiated with $1 \times 10^{14}$ ions/cm$^2$ $^{26}$Fe$^{21+}$ ions incident depth at different locations (2, 5, 10, 20, 25, 32, 35 and 40 microns away from the samples surface along the ion incident depth orientation, SRIM calculated that 350 MeV $^{56}$Fe$^{21+}$ ion incident depth in ZnO is about 35 microns) were measured, and the incident light was perpendicular to the axis [0001]. In Figure 2, there is no $A_1$(LO) pattern in the pristine sample shown with the black line. However, a strong peak appeared at 576 cm$^{-1}$ after $^{56}$Fe$^{21+}$ ion irradiation, which could only indicate that it was the absorption peak of oxygen vacancy ($V_o$) related defects. The absorption band of 80 cm$^{-1}$–245 cm$^{-1}$ shows interstitial zinc ($Zn_i$) defects, and the absorption band of the defects was obviously enhanced after $^{56}$Fe$^{21+}$ ion irradiation. It may be seen from the figure that the other Raman characteristic lines have no significant variation tendency.
At the same time, from the corresponding electron diffraction pattern on the right, the diffraction points were determined by TEM measurement, which were 0.258, 0.19, 0.22 and 0.280 nm, respectively.

A series of changes took place in the arrangement of atoms, including interstitial atoms, dislocations, vacancies, and other defects. The distances between planes in different directions (002), (200), (111) and (100) were measured. Direction of the laser was along the axis [0001] of the crystal. The ZnO structure of wurtzite is shown in the figure. The Raman peaks are assigned by corresponding atomic oscillations (the motion of the dominant atom is indicated by the red arrow).

Figure 1. Raman spectra of ZnO irradiated and unirradiated by $^{56}\text{Fe}^{21+}$ ions were measured. Direction of the laser was along the axis [0001] of the crystal. The ZnO structure of wurtzite is shown in the figure. The Raman peaks are assigned by corresponding atomic oscillations (the motion of the dominant atom is indicated by the red arrow).

Figure 2. Raman spectra (incident light is perpendicular to the axis [0001]) of ZnO irradiated by $^{56}\text{Fe}^{21+}$ ion with irradiation dose of $1 \times 10^{14}$ ions/cm$^2$. The incident ions were along [0001] of the crystal. The ZnO structure of wurtzite is shown in the figure. The Raman peaks are described by corresponding atomic oscillations. (The motion of the dominant atom is indicated by the red arrows).

3.2. TEM of ZnO Irradiated with $^{56}\text{Fe}^{21+}$ Ions

Figure 3 presents a high resolution electron microscope photograph of ZnO irradiated with $1 \times 10^{14}$ ions/cm$^2$ $^{256}\text{Fe}^{21+}$ ions incident depth at different locations (It is 2, 10, 25 and 32 microns away from the samples surface) along the incident depth orientation of $^{56}\text{Fe}^{21+}$ ions. As shown, after irradiation, a series of changes took place in the arrangement of atoms, including interstitial atoms, dislocations, vacancies, and other defects. The distances between planes in different directions (002), (200), (111) and (100) were determined by TEM measurement, which were 0.258, 0.19, 0.22 and 0.280 nm, respectively. At the same time, from the corresponding electron diffraction pattern on the right, the diffraction points...
in the samples were clear and orderly, and no noticeable amorphous phenomena appeared, which indicates that the higher energy (350 MeV) and higher irradiation dose (1 × 10^{14} ions/cm^{2}) hardly affected the structure and performance of the entire zinc oxide.

Figure 3. TEM images and corresponding diffraction patterns of 56Fe^{21+} ion irradiated ZnO at different depths ((a) is 2 µm, (b) is 10 µm, (c) is 25 µm, (d) is 32 µm) along the incident direction of 56Fe^{21+} ions. Irradiation doses of heavy ions were 1 × 10^{14} ions/cm^{2}.

3.3. Photoluminescence Spectra of ZnO Irradiated with 56Fe^{21+} Ions

Photoluminescence is very sensitive to crystal structure defects. ZnO interband excitation causes electrons to jump from valence band to conduction band, leaving holes in the valence band. These holes migrate from the valence electron band to the deep level and recombine between the electrons in the conduction band or the shallow level and the capture hole in the deep level. The photoluminescence spectra of ZnO irradiated with 56Fe^{21+} ions and unirradiated are shown in Figure 4. With a gradual increase of irradiation dose, the characteristic luminescent peak of ZnO decreases rapidly, and various defective luminescent peaks appear at 5 × 10^{13} ions/cm^{2} dose. Experimental data (black line) were fitted with Voigt peaks, the red curve represents the sum of fitted peaks (green peaks) plus the background in Figure 5. It is generally believed that in zinc oxide, oxygen vacancy (Vo), and interstitial zinc (Zni) are the donors, and zinc vacancy (Vzn) and interstitial oxygen (Oi) are the receptors [19,20]. In our experiment, an emission at around 410 nm may be related to the transition of electrons from the shallow donor level of Zni to the top level of the valence band. Emission at around 430 nm was associated with ZnO nanoparticles. The blue emission at about 450 nm may be attributed to the transition from the extended Zni state (slightly lower than the simple Zni state) to the valence band [20]. The red emission at about 580 nm, 640 nm, and 710 nm suggests that different Fe-related emitting centers coexist in ZnO irradiated with 350 MeV 56Fe^{21+} ions.

Figure 4. PL spectra of ZnO irradiated with 56Fe^{21+} ions measured by excited light at 340 nm. The image on the upper right is a panorama of the image.
A hexagonal fiber zinc structure is one of the most stable crystal structures with chemical characteristics. The lattice has hexagonal symmetry and belongs to $\text{C}_{6h}^1$ space group. The Zn and O atoms in the crystal form a simple hexagonal lattice. Each primitive cell consists of two ZnO molecular units consisting of four atoms. There are eight optical vibrational modes at $\Gamma$ point of the Brillouin zone center, which are expressed as: $\Gamma_{\text{opt}} = A_1 + 2B_1 + E_1 + 2E_2$ [21]. $A_1$ and $E_1$ are polar lattice vibrational modes, which are optical vibrational modes with Raman and infrared activities. Because the propagation direction is perpendicular to the axis [0001] symmetry, these modes are divided into $E_1$(LO) (588 cm$^{-1}$) and $A_1$(TO) (380 cm$^{-1}$) (LO, longitudinal optics. TO, transverse Optics). Polarization-induced mode $E_1$(TO) (410 cm$^{-1}$) and $A_1$(LO) (576 cm$^{-1}$) propagate parallel to the $z$ axis in infrared region. In the first region of Brillouin $A_1$, $E_1$ is doubly degenerate, $E_2$ (low is 101 cm$^{-1}$, high is 438 cm$^{-1}$) has Raman activity and $B_1$ have no Raman activity. According to the lattice dynamics equation can calculate the phonon dispersion relations of wurtzite zinc oxide at $\Gamma$ point in a particular orientation of the Brillouin zone center. As shown in Figure 6, there are three groups of optical modes in the high frequency range, namely, $E_1$(LO), $A_1$(LO) and $B_1$(high). $E_2$(high), $E_1$(TO) and $A_1$(TO) appear between 350 cm$^{-1}$ to 550 cm$^{-1}$ frequency range, and the low frequency has a single characteristic frequency which belongs to $B_1$(low) and $E_2$(low), respectively.

Figure 5. PL spectra of ZnO irradiated with $1 \times 10^{13}$ ions/cm$^2$ $^{56}$Fe$^{21+}$ ions. Experimental data (black line) were fitted with Voigt peaks, the red curve represents the sum of fitted peaks (green peaks) plus background.

3.4. Theoretical Calculation and Discussion

Figure 6. Phonon dispersion relationship of wurtzite zinc oxide are calculated at $\Gamma$ point in the specified direction of the Brillouin zonecenter by using the lattice dynamics equation. Molecular vibration represented by red font ($E_1$, $E_2$, $A_1$) can be observed through Raman scattering, while $B_1$ mode represented by green font can’t be observed through Raman scattering.
R. Loudon et al. [22] calculated the following five Raman tensors of ZnO:

\[
\psi_{A1} = \begin{pmatrix}
\alpha' & 0 & 0 \\
0 & \alpha' & 0 \\
0 & 0 & \beta'
\end{pmatrix},
\psi_{E1(\bar{y})} = \begin{pmatrix}
0 & 0 & -\beta' \\
0 & 0 & 0 \\
-\beta' & 0 & 0
\end{pmatrix},
\psi_{E1(y)} = \begin{pmatrix}
0 & 0 & 0 \\
0 & 0 & -\beta' \\
0 & \beta' & 0
\end{pmatrix},
\psi_{E2(x)} = \begin{pmatrix}
0 & 0 & 0 \\
0 & 0 & 0 \\
\beta' & 0 & 0
\end{pmatrix},
\psi_{E2(y)} = \begin{pmatrix}
0 & 0 & 0 \\
0 & -\beta' & 0 \\
0 & 0 & 0
\end{pmatrix}
\]

The Raman scattering strength is related to the polarization strength vectors \(\vec{e}_i\) and \(\vec{e}_s\) of the incident and scattered beam, that is, \(\beta = C|\vec{e}_i, \psi, \vec{e}_s|^2\). C is a constant, \(\psi\) is Raman tensor of phonon \(\delta\). Different Raman spectra may be measured by selecting the appropriate polarization orientation of incident beam. For instance, if we set the polarization strength vectors to \(\vec{e}_i = (0, \cos \alpha, \sin \alpha), \vec{e}_s = (0, \cos \alpha, \sin \alpha)^T\), using the backscatter geometry \(x(e_x, e_y)\) [23,24]. \(\alpha\) is the angle between the incident light polarization orientation and the y axis. According to the above formula, it is possible to calculate the scattering strength \(\beta_{A1}\) of \(A1\) phonon, \(\beta_{E1(\bar{y})}\) of \(E1(\bar{y})\), \(\beta_{E1(y)}\) of \(E1(y)\), \(\beta_{E2(\bar{y})}\) of \(E2(\bar{y})\), and \(\beta_{E2(y)}\) of \(E2(y)\):

\[
\beta_{E1(\bar{y})} = \left(\begin{array}{ccc}
0 & 0 & 0 \\
\cos \alpha & 0 & 0 \\
-\cos \alpha & 0 & 0
\end{array}\right) = 0
\]

\[
\beta_{E1(y)} = \left(\begin{array}{ccc}
0 & 0 & 0 \\
\cos \alpha & 0 & 0 \\
-\cos \alpha & 0 & 0
\end{array}\right) = C \cos^2 \alpha
\]

\[
\beta_{E2(\bar{y})} = \left(\begin{array}{ccc}
0 & 0 & 0 \\
\cos \alpha & 0 & 0 \\
-\cos \alpha & 0 & 0
\end{array}\right) = C \cos^2 \alpha
\]

\[
\beta_{E2(y)} = \left(\begin{array}{ccc}
0 & 0 & 0 \\
\cos \alpha & 0 & 0 \\
-\cos \alpha & 0 & 0
\end{array}\right) = C \cos^2 \alpha
\]

\[
\beta_{A1} = \left(\begin{array}{ccc}
0 & 0 & 0 \\
\cos \alpha & 0 & 0 \\
-\cos \alpha & 0 & 0
\end{array}\right) = 0
\]

The \(\beta_{A1}\) consequence is that the \(A1\) mode is a vibration parallel to the axis [0001] of the crystal and the polarization orientation is non-degenerate along the axis [0001] direction. Figure 1 shows the propagation direction of incident light along the axis [0001], the scattering strength of \(E1(y)\) phonon \(\beta_{E1(y)} = 0\) and the vibrational mode of \(A1(LO)\) appeared at 576 cm\(^{-1}\). The \(E1\) mode is the vertical axis [0001] vibration in the XY plane. The scattering strength of \(A1\) phonon is \(\beta_{A1} = 0\), only when the incident light orientation travel in the vertical z-axis plane and the \(E1(LO)\) (588 cm\(^{-1}\)) mode is observed. These are confirmed in Figure 2. Therefore, after irradiation, it’s easy to distinguish between \(A1(LO)\) and the oxygen vacancy \((V_o)\), which are changing. Both \(E2(LO)\) and \(E2(LO)\) modes can be detected simultaneously. This is due to the fact that the \(E2(LO)\) mode is only associated with the vibration of \(Zn\) atoms, while the \(E2(LO)\) mode is only associated with the vibration of \(O\) atoms. All of these are caused by a large number of interstitial oxygen and interstitial zinc atoms after 350 MeV \(^{56}\)Fe\(^{21+}\) ion irradiation. Correspondingly, the absorption band of zinc interstitial \((Zn)\) defects was about 586--245 cm\(^{-1}\), and \(V_o\) at 576 cm\(^{-1}\) was detected. The strength of these absorption bands was relevant to the radiation influences of 350 MeV \(^{56}\)Fe\(^{21+}\) ions. This completely demonstrates the vibrational absorption peak at 576 cm\(^{-1}\) after irradiation with \(^{56}\)Fe\(^{21+}\) ions is \(V_o\), rather than the vibration mode of \(A1(LO)\).
4. Conclusions

Raman spectra, PL spectra and TEM images of ZnO single crystals irradiated by 350 MeV\(^{56}\)Fe\(^{21+}\) ions were studied. The experimental data showed that numerous of defects associated with oxygen vacancies and interstitial zinc were produced in ZnO after irradiated with \(^{56}\)Fe\(^{21+}\) ions. Through theoretical calculation and experimental testing, it was determined that the vibrational absorption peak at 576 cm\(^{-1}\) after irradiation with \(^{56}\)Fe\(^{21+}\) ions was due to the oxygen vacancy defect (V\(_{o}\)), rather than the eigenmode of A\(_1\)(LO). The Raman spectra showed that the absorption peak of oxygen defects increased with an increase of dose, and reached a saturation state with a 5 \(\times\) 10\(^{13}\) ions/cm\(^2\) dose, which indicated that the local structure of ZnO single crystals had been destroyed after irradiation. However, with the other eigenmode, almost no change took place, i.e., a wurtzite structure was retained. It is difficult to produce amorphous crystals, even after swift heavy ion irradiation. The results show that ZnO has excellent radiation resisting properties.

**Author Contributions:** Y.S. was responsible for writing manuscripts, irradiation experiments, testing and analysis, etc. S.Z. participated in the test and analysis of Raman data, Y.Y. and C.Z. participated in research design, data analysis and other work, K.L. participated in ion beam irradiation experiments.

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